P-Channel 40-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, cellular and cordless telephones.

PRODUCT SUMMARY					
$\boxed{V_{DS}\left(V\right) \qquad \qquad r_{DS(on)}m(\Omega) \qquad \qquad I_{D}\left(A\right)}$					
-40	$28 @ V_{GS} = -10V$	-6.6			
-40	$45 @ V_{GS} = -4.5V$	-5.2			

- $\begin{tabular}{ll} \bullet & Low \ r_{DS(on)} \ provides \ higher \ efficiency \ and \\ extends \ battery \ life \end{tabular}$
- Low thermal impedance copper leadframe TSSOP-8 saves board space
- Fast switching speed
- High performance trench technology

	TSSOP-8			
	Top View			S
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D 1		8	□ D	G⊶Ļ↓
S 2		7	S	5
S 3		6	⊥ S	70
G 4		5	□ N/C	U
		١ -		P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)						
Parame te r			Maximum	Units		
Drain-Source Voltage			-40	V		
Gate-Source Voltage			±20	v		
Continuous Drain Current ^a	T _A =25°C	Τ_	-6.6			
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	-5.4	A		
Pulsed Drain Current ^b			-30			
Continuous Source Current (Diode Conduction) ^a			-1.5	A		
Daniel Distriction ^a	$T_A=25^{\circ}C$	D_	1.8	W		
Power Dissipation ^a	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	Гр	1.2	• • • • • • • • • • • • • • • • • • • •		
Operating Junction and Storage Temperature Range			-55 to 150	°C		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Maximum	Units		
NA	t <= 10 sec	D	70	°C/W		
Maximum Junction-to-Ambient ^a	Steady State	$ m R_{ heta JA}$	115			

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Analog Power AM6441P

SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)								
Parameter	Cyynah ol	Total Conditions	Limits			Unit		
rarameter	Symbol	Test Conditions	Min	Тур	Max	Unit		
Static	-							
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$	-1					
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA		
Zero Gate Voltage Drain Current	$I_{ m DSS}$	$V_{DS} = -32 \text{ V}, V_{GS} = 0 \text{ V}$			-1	11.Δ		
Zero Gate Voltage Drain Current	¹ DSS	$V_{DS} = -32 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-10	uA		
On-State Drain Current ^A	$I_{D(on)}$	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-20			A		
Drain-Source On-Resistance ^A		$V_{GS} = -10 \text{ V}, I_{D} = -1 \text{ A}$			28	mΩ		
Drain-Source On-Resistance	$r_{\mathrm{DS(on)}}$	$V_{GS} = -4.5 \text{ V}, I_D = -1 \text{ A}$			45			
Forward Tranconductance ^A	$g_{ m fs}$	$V_{DS} = -15 \text{ V}, I_{D} = -1 \text{ A}$		45		S		
Diode Forward Voltage	V_{SD}	$I_S = 1 A, V_{GS} = 0 V$		-0.6		V		
Dynamic ^b								
Total Gate Charge	Q_{g}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V},$		16		nC		
Gate-Source Charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.3 \text{ V},$ $I_{D} = -1 \text{ A}$		4				
Gate-Drain Charge	Q_{gd}	1 _D – -1 A		6				
Turn-On Delay Time	$t_{d(on)}$			9				
Rise Time	t _r	$V_{DD} = -10 \text{ V}, R_L = 6 \Omega$, $ID = -1 \text{ A},$		10		nS		
Turn-Off Delay Time	$t_{d(off)}$	VGEN = -4.5 V		60] "13		
Fall-Time	t_{f}			20				

Notes

- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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